## NSN 5961-01-325-1446

**Fiig:** A110a0

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-325-1446 **Inclosure Material:** Ceramic and metal **Overall Length:** Between 0.545 inches and 0.605 inches **Overall Diameter:** Between 1.850 inches and 1.900 inches **Mounting Method:** Press fit **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 1200.0 repetitive peak off-state voltage and 1200.0 repetitive peak reverse voltage **Current Rating Per Characteristic:** 650.00 amperes drain current universal **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Terminal Type And Quantity:** 2 case and 2 insulated wire lead w/terminal lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** No